

THE DATASHEET OF **SN75185DB**

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0086-755-83957316



FEATURES

- Single Chip With Easy Interface Between **UART and Serial-Port Connector of** IBM[™] PC/AT[™] and Compatibles
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Supports Data Rates up to 120 kbit/s
- ESD Protection Meets or Exceeds 10 kV on RS-232 Pins and 3.5 kV on All Other Pins (Human-Body Model)
- Pin-to-Pin Compatible With the SN75C185

DESCRIPTION/ORDERING INFORMATION

The SN75185 combines three drivers and five receivers from the TI SN75188 and SN75189 bipolar guadruple drivers and receivers, respectively. The pinout matches the flow-through design of the SN75C185 to decrease the part count, reduce the board space required, and allow easy interconnection of the UART and serial-port connector of IBM™ PC/AT[™] and compatibles. The bipolar circuits and processing of the SN75185 provide a rugged low-cost solution for this function at the expense of guiescent power and external passive components relative to the SN75C185.

The SN75185 complies with the requirements of the TIA/EIA-232-F and ITU v.28 standards. These standards are for data interchange between a host computer and peripheral at signaling rates up to 20 kbit/s. The switching speeds of the SN75185 are fast enough to support rates up to 120 kbit/s with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be assured unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates to 120 kbit/s, use of TIA/EIA-423-B (ITU v.10) and TIA/EIA-422-B (ITU v.11) standards is recommended.

The SN75185 is characterized for operation over the temperature range of 0°C to 70°C.

-		CKAGE VIEW)	_
V _{DD} [RA1 [RA2 [RA3 [DY1 [DY2 [RA4 [DY3 [RA5 [V _{SS} [1 2 3 4 5 6 7 8 9 10	20 19 18 17 16 15 14 13 12 11	V _{CC} RY1 RY2 RY3 DA1 DA2 RY4 DA3 RY5 GND

DB, DW, OR PW PACKAGE (TOP VIEW)

V _{DD} RA1 RA2 RA3	1 2 3 4	20 19 18 17	□ V _{CC} □ RY1 □ RY2 □ RY3
DY1 🖂	5	16	💷 DA1
DY2 🖂	6	15	DA2
RA4 🖂	7	14	💷 RY4
DY3 🖵	8	13	💷 DA3
RA5 💷	9	12	💷 RY5
V _{SS} □──	10	11	=== GND



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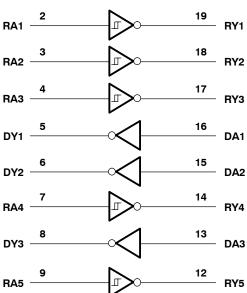
SN75185 **MULTIPLE RS-232 DRIVERS AND RECEIVERS**

SLLS181D-DECEMBER 1994-REVISED JANUARY 2006

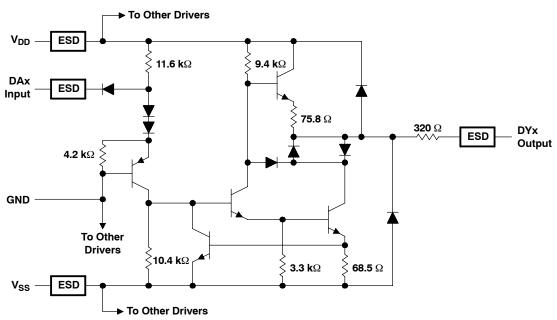
ORDERING INFORMATION

T _A	P/	ACKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 20	SN75185N	SN75185N
	SOIC - DW	Tube of 25	SN75185DW	ON/76106
	50IC - DW	Reel of 2000	SN75185DWR	— SN75185
0°C to 70°C	SSOP – DB	Tube of 70	SN75185DB	A185
	330F - DB	Reel of 2000	SN75185DBR	A105
	TSSOP – PW	Tube of 70	SN75185PW	A105
	1330F - PW	Reel of 2000	SN75185PWR	— A185

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

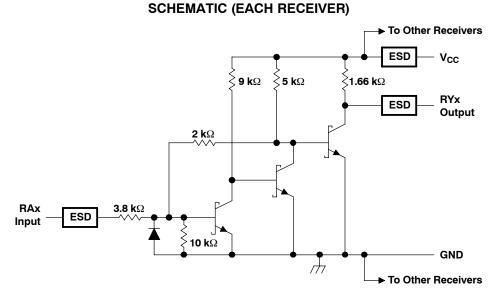


LOGIC DIAGRAM (POSITIVE LOGIC)



SCHEMATIC OF DRIVERS

Resistor values shown are nominal.



Resistor values shown are nominal.

SN75185 **MULTIPLE RS-232 DRIVERS AND RECEIVERS**



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT	
V _{CC}	Supply voltage ⁽²⁾				10	V	
V _{DD}	Supply voltage ⁽²⁾				15	V	
V _{SS}	Supply voltage ⁽²⁾	Driver					
		Driver		-15	7	V	
	Input voltage range	Receiver		-30	30	v	
	Driver output voltage range			-15	15	V	
	Receiver low-level output current				20	mA	
		DB package	DB package				
	Decline thermal impedance $^{(3)}(4)$	DW package	DW package				
θ_{JA}	Package thermal impedance ⁽³⁾⁽⁴⁾	N package			69	°C/W	
		PW package	PW package				
TJ	Operating virtual junction temperature				150	°C	
		Liuman Dadu Madal	RS-232 pins, class 3, A ⁽⁵⁾		10	kV	
	Floatrostatio discharge	Human-Body Model	All pins, class 3, A ⁽⁶⁾		3.5	ĸv	
	Electrostatic discharge	Mashina Madal	RS-232 pins, class 3, B ⁽⁷⁾		600	N/	
		wachine wodel	Machine Model All pins, class 3, B ⁽⁵⁾				
T _{stg}	Storage temperature range			-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2)

All voltages are with respect to the network ground terminal. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7. (3)

(4)

(5) RS-232 pins are tested with respect to ground and to each other.

Per MIL-PRF-38535 (6)

(7) RS-232 pins are tested with respect to ground.

Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		4.5	5	5.5	V
V _{DD}	Supply voltage		7.5	9	15	V
V _{SS}	Supply voltage		-7.5	-9	-15	V
VIH	High-level input voltage (drivers only)		1.9			V
VIL	Low-level input voltage (drivers only)				0.8	V
	High level output ourrept	Drivers			-6	mA
IOH	High-level output current	Receivers			-0.5	IIIA
		Drivers			6	
IOL	Low-level output current	Receivers			16	mA
T _A	Operating free-air temperature		0		70	°C

Supply Currents

	PARAMETER		TEST C	ONDITIONS		MIN	MAX	UNIT
I _{CC}	Supply current from V_{CC}	All inputs at 5 V,	No load,	$V_{\rm CC} = 5 \ V$			30	mA
				V _{DD} = 9 V,	$V_{SS} = -9 V$		15	
		All inputs at 1.9 V,	No load	$V_{DD} = 12 V$,	$V_{SS} = -12 V$		19	
	Supply current from VDD			$V_{DD} = 15 V,$	$V_{SS} = -15 V$		25	mA
IDD	Supply current from v _{DD}			V _{DD} = 9 V,	$V_{SS} = -9 V$		4.5	ША
		All inputs at 0.8 V,	No load	$V_{DD} = 12 V,$	$V_{SS} = -12 V$		5.5	
				V _{DD} = 15 V,	V _{SS} = -15 V		9	
				V _{DD} = 9 V,	V _{SS} = -9 V		-15	
		All inputs at 1.9 V,	No load	V _{DD} = 12 V,	V _{SS} = -12 V		-19	
	Supply ourrent from V			$V_{DD} = 15 V$,	V _{SS} = -15 V		-25	mA
I _{SS}	Supply current from V_{SS}			V _{DD} = 9 V,	V _{SS} = -9 V		-3.2	ША
		All inputs at 0.8 V,	No load	V _{DD} = 12 V,	V _{SS} = -12 V		-3.2	
				V _{DD} = 15 V,	V _{SS} = -15 V		-3.2	

SN75185 **MULTIPLE RS-232 DRIVERS AND RECEIVERS**

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DRIVER SECTION

Electrical Characteristics

over recommended operating free-air temperature range, V_{DD} = 9 V, V_{SS} = -9 V, V_{CC} = 5 V (unless otherwise noted)

	PARAMETER		TEST CONDITIONS					UNIT
V _{OH}	High-level output voltage	V _{IL} = 0.8 V,	$R_L = 3 k\Omega$,	See Figure 1	6	7.5		V
V _{OL}	Low-level output voltage ⁽¹⁾	V _{IH} = 1.9 V,	$R_L = 3 k\Omega$,	See Figure 1		-7.5	-6	V
I _{IH}	High-level input current	V ₁ = 5 V,	See Figure 2				10	μA
IIL	Low-level input current	V ₁ = 0,	See Figure 2				-1.6	mA
I _{OS(H)}	High-level short-circuit output current ⁽²⁾	V _{IL} = 0.8 V,	V _O = 0,	See Figure 1	-4.5	-12	-19.5	mA
I _{OS(L)}	Low-level short-circuit output current	V _{IH} = 2 V,	V _O = 0,	See Figure 1	4.5	12	19.5	mA
r _o	Output resistance ⁽³⁾	$V_{CC} = V_{DD} = V_{S}$	_{SS} = 0,	$V_0 = -2 V$ to 2 V	300			Ω

The algebraic convention, in which the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic (1) levels only (e.g., if -10 V is maximum, the typical value is a more negative voltage).

Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings. Test conditions are those specified by TIA/EIA-232-F and as listed above. (2)

(3)

Switching Characteristics

 V_{CC} = 5 V, V_{DD} = 12 V, V_{SS} = –12 V, T_A = 25°C (see Figure 3)

	PARAMETER	TEST C	ONDITIONS	MIN	ТҮР	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	$R_L = 3 \ k\Omega$ to 7 $k\Omega$,	C _L = 15 pF		315	500	ns
t _{PHL}	Propagation delay time, high- to low-level output	$R_L = 3 \ k\Omega$ to 7 $k\Omega$,	C _L = 15 pF		75	175	ns
+	Transition time, low- to high-level output	$R_1 = 3 k\Omega$ to 7 k Ω	C _L = 15 pF		60	100	ns
t _{TLH}	Transition time, low- to high-level output	$H_{L} = 3 KS2 10 7 KS2$	C _L = 2500 pF ⁽¹⁾		1.7	2.5	μs
	Transition time, high to low loval autout		C _L = 15 pF		40	75	ns
t _{THL}	Transition time, high- to low-level output	$R_L = 3 k\Omega \text{ to } 7 k\Omega$	C _L = 2500 pF ⁽²⁾		1.5	2.5	μs

Measured between -3-V and 3-V points of the output waveform (TIA/EIA-232-F conditions); all unused inputs are tied either high or low. (1) Measured between 3-V and -3-V points of the output waveform (TIA/EIA-232-F conditions); all unused inputs are tied either high or low. (2)

RECEIVER SECTION

Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST C	MIN	TYP ⁽¹⁾	MAX	UNIT	
v	Depitive action threader and welters	One Figure F	T _A = 25°C	1.75	1.9	2.3	v
V_{T+}	Positive-going threshold voltage	See Figure 5	$T_A = 0^\circ C$ to $70^\circ C$	1.55		2.3	v
V_{T-}	Negative-going threshold voltage			0.75	0.97	1.25	V
V _{hys}	Input hysteresis (V _{T+} – V _{T–})			0.5	·		V
V		0.5 m (V _{IH} = 0.75 V	2.6	4	5	v
V _{OH}	High-level output voltage	I _{OH} =0.5 mA	Inputs open	2.6			V
V _{OL}	Low-level input voltage	I _{OL} = 10 mA,	V _I = 3 V		0.2	0.45	V
		V _I = 25 V,	See Figure 5	3.6	·	8.3	
IIH	High-level input current	V ₁ = 3 V,	See Figure 5	0.43			mA
		V _I = -25 V,	See Figure 5	-3.6		-8.3	
IIL	Low-level output current	$V_{I} = -3 V,$	See Figure 5	-0.43			mA
I _{OS}	Short-circuit output current	See Figure 4			-3.4	-12	mA

(1) All typical values are at T_A = 25°C, V_{CC} = 5 V, V_{DD} = 9 V, and V_{SS} = –9 V.

Switching Characteristics

 V_{CC} = 5 V, V_{DD} = 12 V, V_{SS} = -12 V, T_{A} = 25°C (see Figure 6)

	PARAMETER	TEST CO	NDITIONS	MIN	ТҮР	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 50 pF,	$R_L = 5 \ k\Omega$		107	500	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 50 pF,	$R_L = 5 \ k\Omega$		42	150	ns
t _{TLH}	Transition time, low- to high-level output	C _L = 50 pF,	$R_L = 5 \ k\Omega$		175	525	ns
t _{THL}	Transition time, high- to low-level output	C _L = 50 pF,	$R_L = 5 \ k\Omega$		16	60	ns

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PARAMETER MEASUREMENT INFORMATION

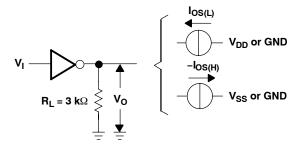


Figure 1. Driver Test Circuit for $V_{\text{OH}},\,V_{\text{OL}},\,I_{\text{OS(H)}},\,\text{and}\,\,I_{\text{OS(L)}}$

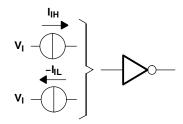
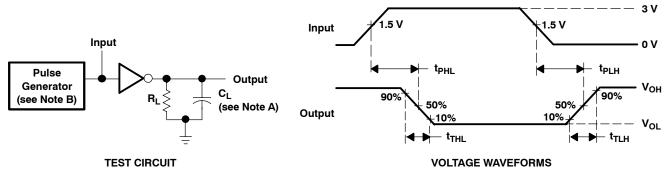


Figure 2. Driver Test Circuit for $I_{\rm IH}$ and $I_{\rm IL}$



A. C₁ includes probe and jig capacitance.

B. The pulse generator has the following characteristics: t_w = 25 μ s, PRR = 20 kHz, Z_O = 50 Ω , t_r = t_f < 50 ns.

Figure 3. Driver Test Circuit and Voltage Waveforms

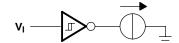
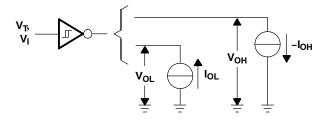
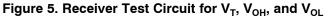


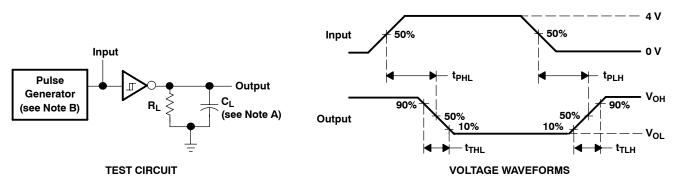
Figure 4. Receiver Test Circuit for IOS







PARAMETER MEASUREMENT INFORMATION (continued)



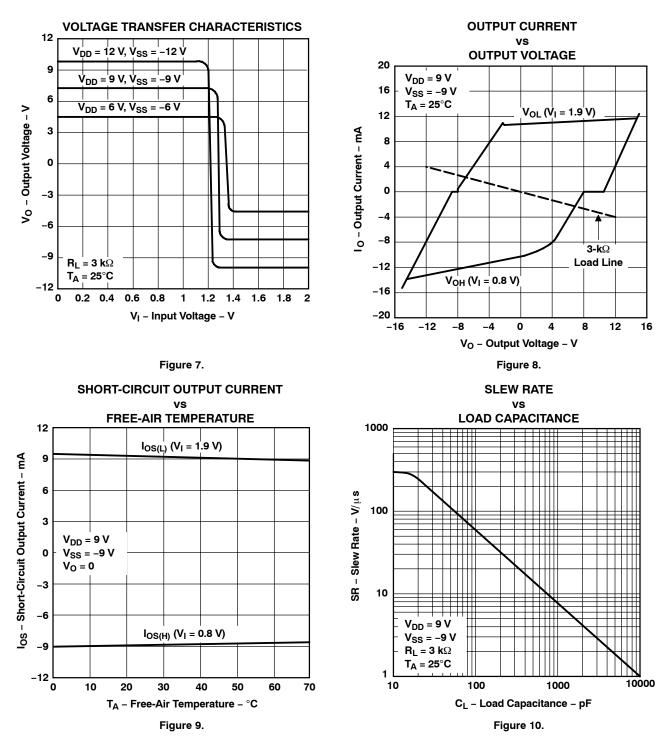
A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: t_w = 25 µs, PRR = 20 kHz, Z_0 = 50 Ω, t_r = t_f < 50 ns.

Figure 6. Receiver Propagation and Transition Times



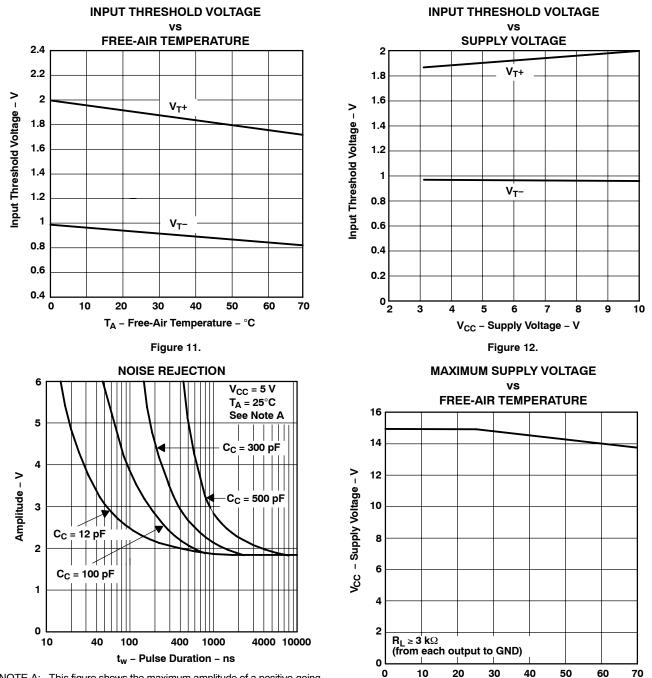
TYPICAL CHARACTERISTICS



DRIVER SECTION

TYPICAL CHARACTERISTICS

RECEIVER SECTION



NOTE A: This figure shows the maximum amplitude of a positive-going pulse that, starting from 0 V, will not cause a change in the output level.

Figure 13.

T_A – Free-Air Temperature – °C

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APPLICATION INFORMATION

Diodes placed in series with the V_{DD} and V_{SS} leads protect the SN75185 in the fault condition. In the fault condition, the device outputs are shorted to ±15 V, and the power supplies are at low and provide low-impedance paths to ground (see Figure 15).

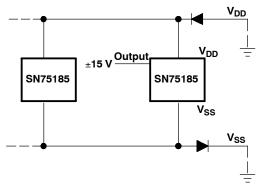
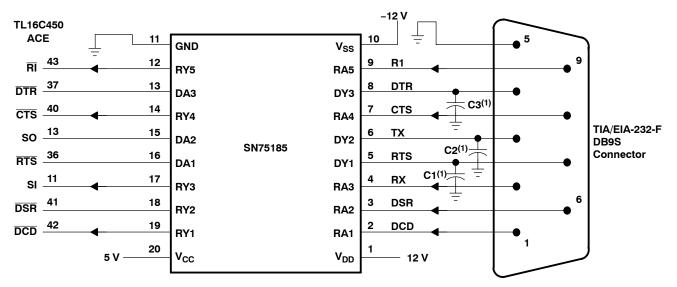


Figure 15. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F



(1) See Figure 10 to select the correct values for the loading capacitors (C1, C2, and C3), which are required to meet the RS-232 maximum slew-rate requirement of 30 V/μs. The value of the loading capacitors required depends on the line length and desired slew rate, but typically is 330 pF.





24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing		Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN75185DB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A185	Samples
SN75185DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A185	Samples
SN75185DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75185	Samples
SN75185DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75185	Samples
SN75185DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75185	Samples
SN75185DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75185	Samples
SN75185N	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75185N	Samples
SN75185PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A185	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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PACKAGE OPTION ADDENDUM

24-Aug-2018

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*Al	dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	SN75185DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
	SN75185DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
	SN75185PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

11-Oct-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75185DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN75185DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN75185PWR	TSSOP	PW	20	2000	367.0	367.0	38.0

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



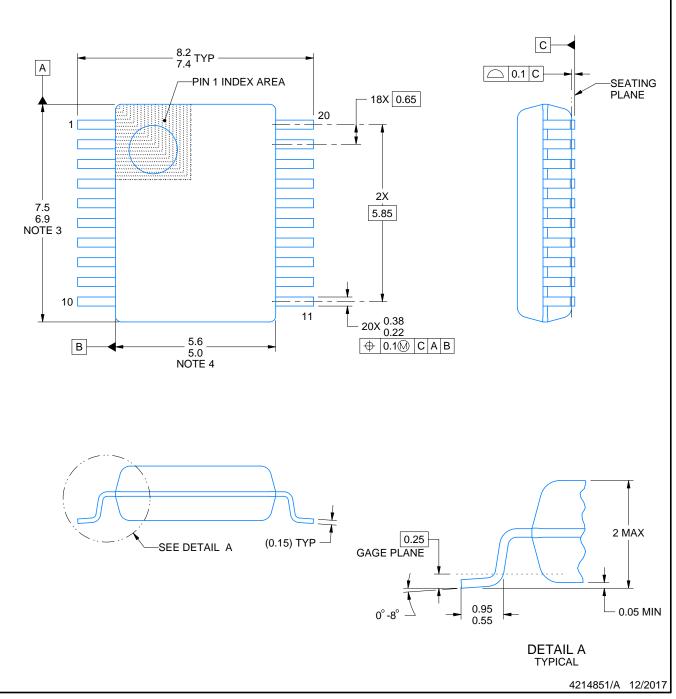
DB0020A



PACKAGE OUTLINE

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.

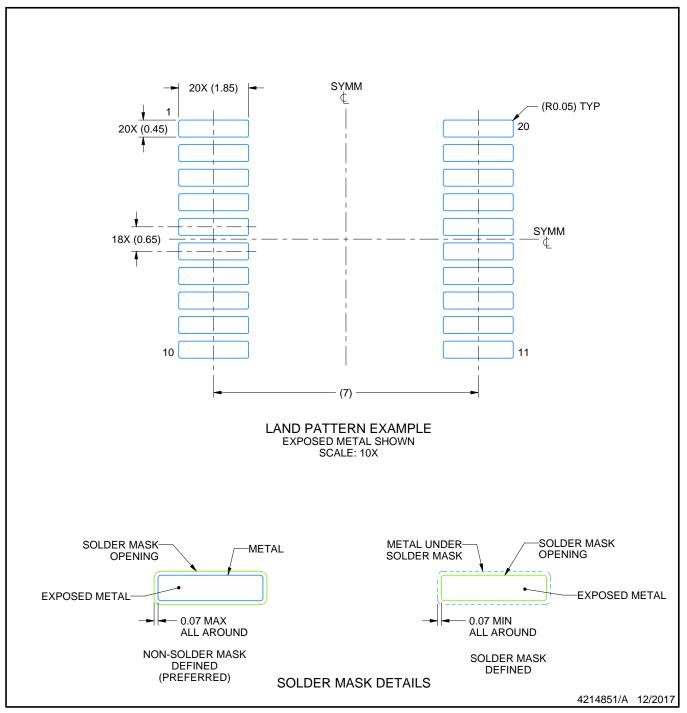


DB0020A

EXAMPLE BOARD LAYOUT

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

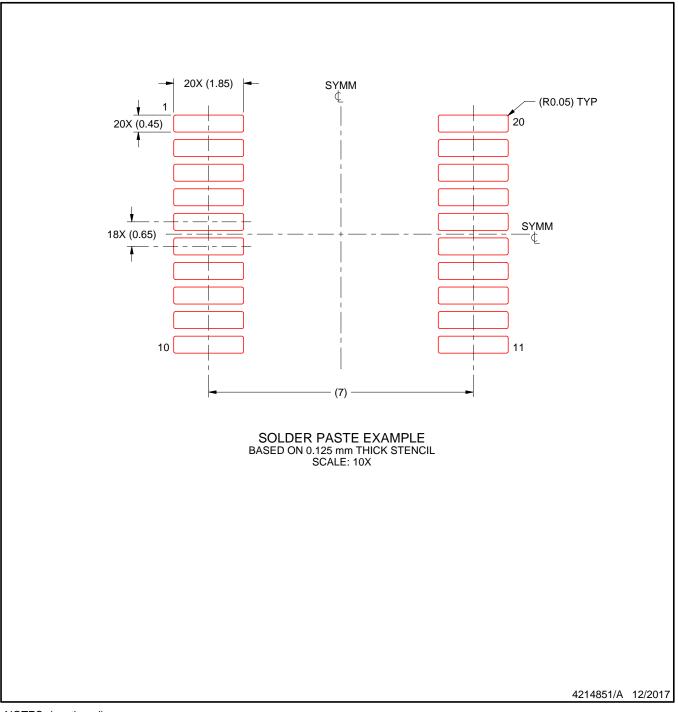


DB0020A

EXAMPLE STENCIL DESIGN

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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